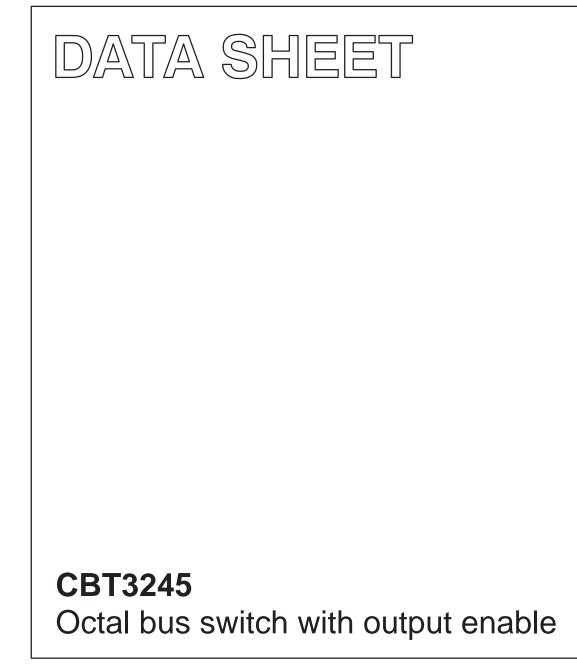
# INTEGRATED CIRCUITS



Preliminary specification

1998 Dec 08



Philips Semiconductors

**CBT3245** 

#### **FEATURES**

- Functionally equivalent to QS3245
- Standard '245-type pinout
- 5Ω switch connection between two ports
- TTL compatible control input levels
- Package options include plastic small outline (D), shrink small outline (DB), thin shrink small outline (TSSOP)

#### DESCRIPTION

The CBT3245 provides eight bits of high-speed TTL-compatible bus switching in a standard '245 device pinout. The low on-state resistance of the switch allows connections to be made with minimal propagation delay.

The CBT3245 device is organized as one 8-bit switch. When enable  $(\overline{OE})$  is low, the switch is on and port A is connected to port B. When  $\overline{OE}$  is high, the switch is open and a high-impedance state exists between the two ports.

The CBT3245 is characterized for operation from -40°C to 85°C.

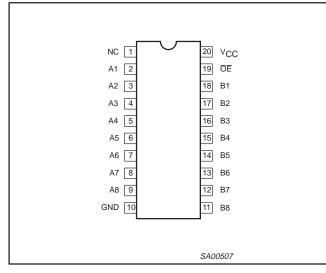
#### QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS T <sub>amb</sub> = 25°C; GND = 0V	TYPICAL	UNIT
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay An to Yn	$C_{L} = 50 pF; V_{CC} = 5V$		ns
C <sub>IO(OFF)</sub>	Pin capacitance (OFF state)	$V_{O} = 3V \text{ or } 0V$	6	pF
I <sub>CCZ</sub>	Total supply current	Outputs disabled; $V_{CC}$ =5.5V		μΑ

#### **ORDERING INFORMATION**

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
20-Pin plastic SO	-40°C to 85°C	CBT3245 D	CBT3245 D	SOT163-1
20-Pin Plastic SSOP Type II	-40°C to 85°C	CBT3245 DB	CBT3245 DB	SOT339-1
20-Pin Plastic TSSOP Type I	-40°C to 85°C	CBT3245 PW	CBT3245PW DH	SOT360-1

#### **PIN CONFIGURATION**

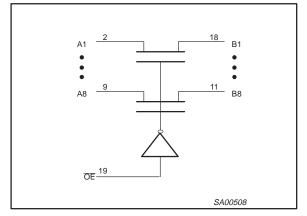


#### **PIN DESCRIPTION**

PIN NUMBER	SYMBOL	NAME AND FUNCTION				
1	NC	No internal connection				
19	ŌĒ	Output enable input				
2, 3, 4, 5, 6, 7, 8, 9	A1–A8					
18, 17, 16, 15, 14, 13, 12, 11	B1–B8					
10	GND	Ground (0V)				
20	V <sub>CC</sub>	Positive supply voltage				

### CBT3245

#### LOGIC SYMBOL



#### **FUNCTION TABLE**

INPUT	INPUTS/OUTPUTS		
OE	A, B		
L	A = B		
н	Z		

H = High voltage level

L = Low voltage level

Z = High impedance "off" state

#### ABSOLUTE MAXIMUM RATINGS<sup>1, 2</sup>

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V <sub>CC</sub>	DC supply voltage		-0.5 to +7.0	V
Ι <sub>ΙΚ</sub>	DC input diode current	V <sub>1</sub> < 0	-50	mA
VI	DC input voltage <sup>3</sup>		-0.5 to +7.0	V
I <sub>OK</sub>	DC output diode current	V <sub>O</sub> < 0	-50	mA
V <sub>OUT</sub>	DC output voltage <sup>3</sup>	output in Off or High state	-0.5 to +7	V
I <sub>OUT</sub>	DC output current	output in Low state	128	mA
T <sub>stg</sub>	Storage temperature range		-65 to 150	°C

#### NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.
The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

## RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIM	UNIT	
	FARAMETER	Min	Max	UNIT
V <sub>CC</sub>	DC supply voltage	4.0	5.5	V
V <sub>IH</sub>	High-level input voltage	2.0		V
V <sub>IL</sub>	Low-level Input voltage		0.8	V
T <sub>amb</sub>	Operating free-air temperature range	-40	+85	°C

### CBT3245

#### **DC ELECTRICAL CHARACTERISTICS**

				LIMITS		
SYMBOL	PARAMETER	TEST CONDITIONS	T <sub>amb</sub> = −40°C to +85°C			UNIT
			Min	Typ <sup>1</sup>	Мах	1
V <sub>IK</sub>	Input clamp voltage	$V_{CC} = 4.5V; I_{I} = -18mA$			-1.2	V
lı	Input leakage current	$V_{CC} = 5.5V; V_{I} = GND \text{ or } 5.5V$			±5	μA
Icc	Quiescent supply current <sup>2</sup>	$V_{CC}$ = 5.5V; $I_O$ = 0, $V_I$ = $V_{CC}$ or GND			50	μΑ
Δl <sub>CC</sub>	Additional supply current per input pin <sup>2</sup>	$V_{CC}$ = 5.5V, one input at 3.4V, other inputs at $V_{CC}$ or GND			3.5	mA
CI	Control pins	$V_{I}$ = 3V or 0, $\overline{OE}$ = $V_{CC}$		3		pF
C <sub>IO(OFF)</sub>	Power-off leakage current	$V_{O} = 3V \text{ or } 0$		6		pF
		$V_{CC} = 4.5V; V_1 = 0V; I_1 = 64mA$		5	7	
r <sub>on</sub> <sup>3</sup>	On-resistance	V <sub>CC</sub> = 4.5V; V <sub>1</sub> = 0V; I <sub>I</sub> = 30mA		5	7	Ω
		$V_{CC} = 4.5V; V_1 = 2.4V; I_1 = 15mA$		10	15	1

NOTES:

1. All typical values are at V<sub>CC</sub> = 5V, TA = 25 C

This is the increase in supply current for each input that is at the specified TTL voltage level rather than V<sub>CC</sub> or GND
Measured by the voltage drop between the A and the B terminals at the indicated current through the switch. On-state resistance is determined by the lowest voltage of the two (A or B) terminals.

### **AC CHARACTERISTICS**

 $GND = 0V; t_{R}; C_L = 50pF$ 

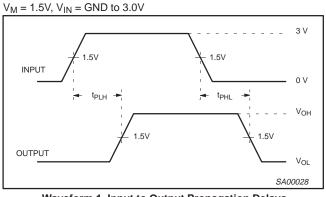
		FROM (INPUT)		74CBT3245 T <sub>amb</sub> = -40°C to +85°C V <sub>CC</sub> = +5.0V ±0.5V			
SYMBOL	PARAMETER		TO (OUTPUT)			UNIT	
				Min	Max		
t <sub>pd</sub>	Propagation delay <sup>1</sup>	A or B	B or A		.25	ns	
t <sub>en</sub>	Output enable time to High and Low level	ŌĒ	A or B			ns	
t <sub>dis</sub>	Output disable time from High and Low level	ŌĒ	A or B			ns	

#### NOTES:

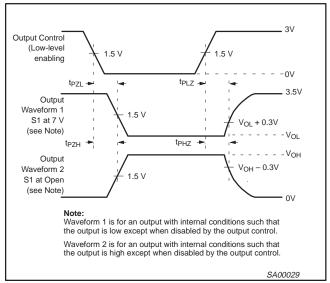
1. This parameter is warranted but not production tested. The propagation delay is based on the RC time constant of the typical on-state resistance of the switch and a load capacitance of 50 pF, when driven by an ideal voltage source (zero output impedance).

### CBT3245

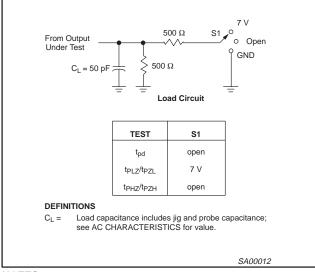
#### AC WAVEFORMS



Waveform 1. Input to Output Propagation Delays



Waveform 2. 3-State Output Enable and Disable Times

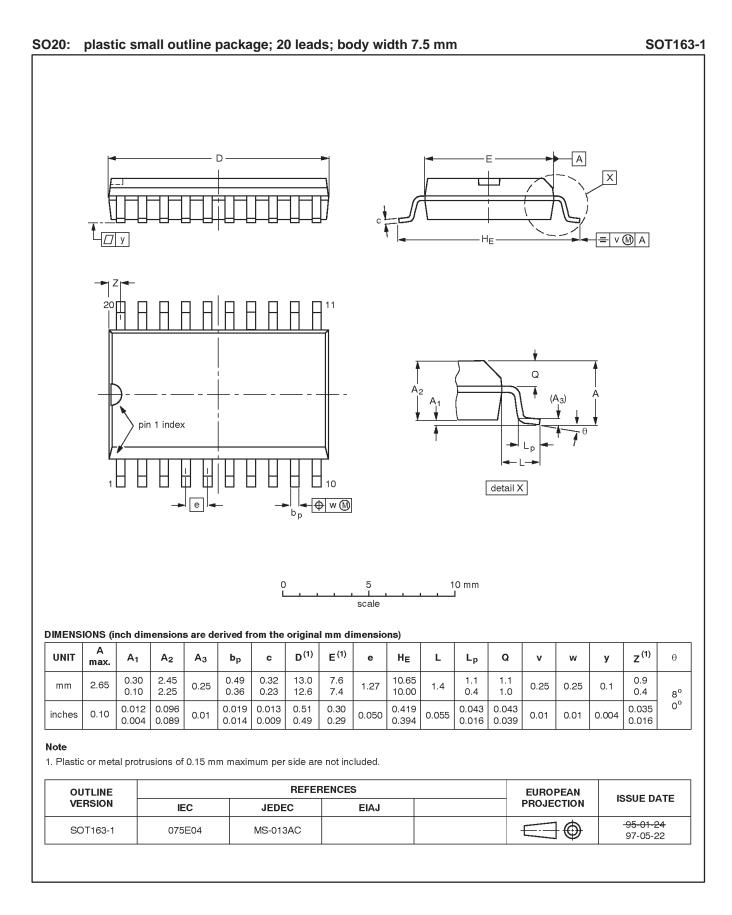


#### NOTES:

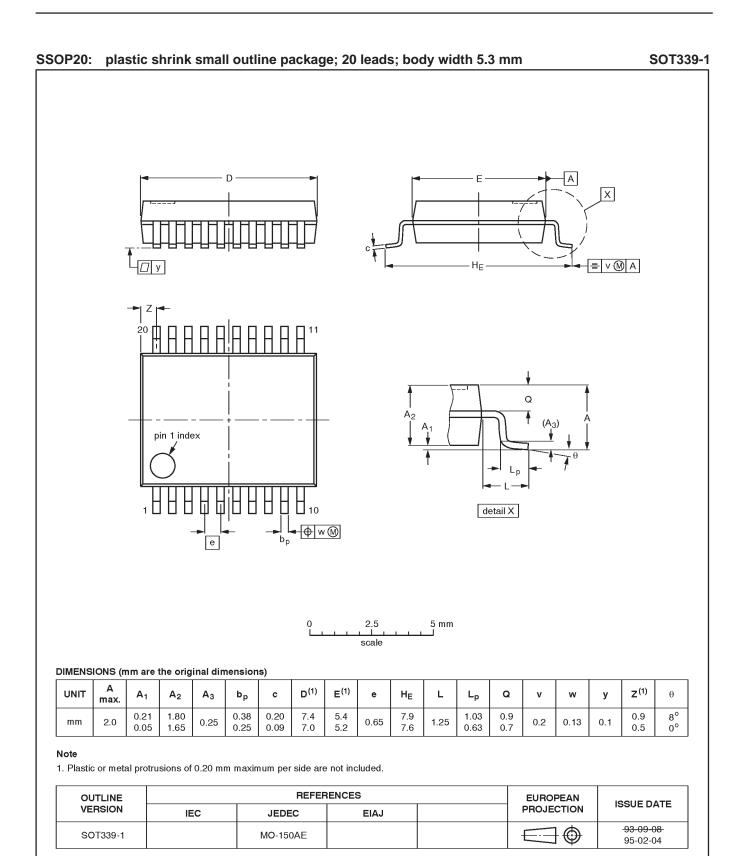
- 1. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>O</sub> = 50  $\Omega$ , t<sub>f</sub>  $\leq$  2.5 ns, t<sub>f</sub>  $\leq$  2.5 ns.
- 2. The outputs are measured one at a time with one transition per measurement.

### TEST CIRCUIT AND WAVEFORMS

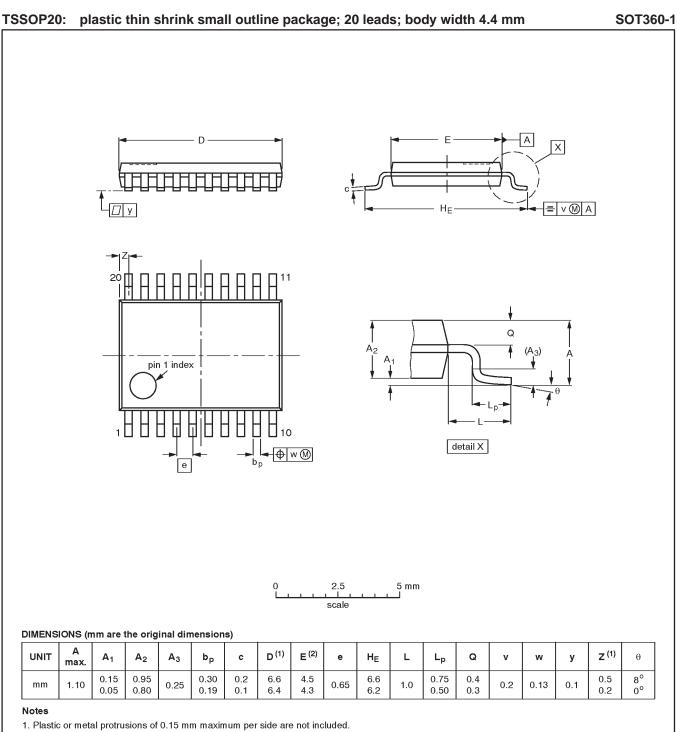
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2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE	TLINE REFERENCES			EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT360-1		MO-153AC				<del>-93-06-16</del> 95-02-04

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NOTES

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#### Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

[1] Please consult the most recently issued datasheet before initiating or completing a design.

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Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition - Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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Document order number:

print code

Date of release: 05-96 9397-750-04607

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